

## **Vishay Semiconductors**

# **Schottky Diodes**

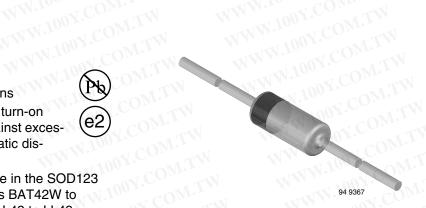
#### **Features**

- · For general purpose applications
- · These diodes feature very low turn-on voltage and fast guard ring against excessive voltage, such as electrostatic discharges
- These diodes are also available in the SOD123 case with the type designations BAT42W to BAT43W and in designations LL42 to LL43.
- · Lead (Pb)-free component
- WWW.100Y.COM.TW WWW.100Y.COM.TW Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Case: DO35 Glass Case Weight: approx. 125 mg Cathode Band Color: black Packaging Codes/Options:

TR / 10 k per 13 " reel (52 mm tape), 50 k/box TAP / 10 k per Ammo tape (52 mm tape), 50 k/box



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#### **Parts Table**

Part	Ordering code	Type Marking	Remarks
BAT42	BAT42-TAP or BAT42-TR	BAT42	Ammopack / Tape and Reel
BAT43	BAT43-TAP or BAT43-TR	BAT43	Ammopack / Tape and Reel

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

amb ,			Y ANY	4.77
Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage	WW. 1007.COM	$V_{RRM}$	30	V
Forward continuous current	T <sub>amb</sub> = 25 °C	IF 1	2001)	mA
Repetitive peak forward current	$t_p$ < 1 s, $\delta$ < 0.5, $T_{amb}$ = 25 °C	I <sub>FRM</sub>	500 <sup>1)</sup>	mA
Surge forward current	t <sub>p</sub> < 10 ms, T <sub>amb</sub> = 25 °C	I <sub>FSM</sub>	41)	A
Power dissipation <sup>1)</sup>	T <sub>amb</sub> = 65 °C	P <sub>tot</sub>	200 <sup>1)</sup>	mW

<sup>1)</sup> Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature WWW.100Y.COM.

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# **BAT42 / BAT43**

### **Vishay Semiconductors**



#### **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Visnay Semiconductors		WWW.100Y.COM.				
Thermal Characteristics T <sub>amb</sub> = 25 °C, unless otherwise specified						
Parameter	Test condition	Symbol	Value	Unit		
Thermal resistance junction to ambient air	MA. 100 A.C.	R <sub>thJA</sub>	300 <sup>1)</sup>	K/W		
Junction temperature	MAN TOOK	T	125	°C		
Ambient operating temperature range	WWW.Iso	T <sub>amb</sub>	- 65 to + 125	.√°C		
Storage temperature range	A. 100 .	T <sub>stg</sub>	- 65 to +150	°C		

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#### **Electrical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	I <sub>R</sub> = 100 μA (pulsed)	10	V <sub>(BR)R</sub>	30	1	-11	00 V
Leakage current	V <sub>R</sub> = 25 V	MM	IR	W	4	0.5	μА
	V <sub>R</sub> = 25 V, T <sub>j</sub> = 100 °C	T.WW.	I <sub>R</sub>	Mr.		100	μА
Forward voltage	I <sub>F</sub> = 200 mA		$V_{F}$	$OM_{JJ}$		1	V
	I <sub>F</sub> = 10 mA	BAT42	$V_{F}$	Time	N	400	mV
	I <sub>F</sub> = 50 mA	BAT42	$V_{F}$	COR	W	650	mV
	I <sub>F</sub> = 2 mA	BAT43	V <sub>F</sub>	260		330	mV
	I <sub>F</sub> = 15 mA	BAT43	$V_{F}$	MOD	.1	450	mV
Diode capacitance	V <sub>R</sub> = 1 V, f = 1 MHz		C <sub>D</sub>	Y.C.	7	V	pF
Reverse recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$	W	t <sub>rr</sub>	OY.CO	M.TW	5	ns
Detection efficiency	$R_L = 15 \text{ k}\Omega, C_L = 300 \text{ pF},$ $f = 45 \text{ MHz}, V_{RF} = 2 \text{ V}$		$\eta_{v}$	80	OM.TY	N	%

### **Typical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

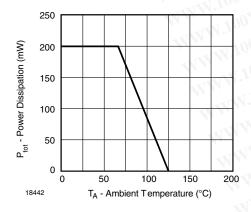


Figure 1. Admissible Power Dissipation vs. Ambient Temperature

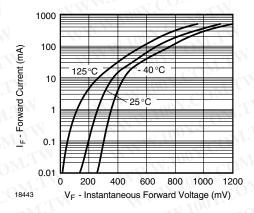


Figure 2. Typical Reverse Characteristics

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<sup>1)</sup> Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature



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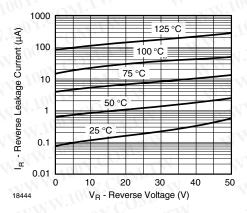


Figure 3. Typical Reverse Characteristics

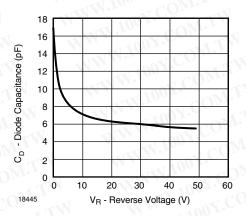
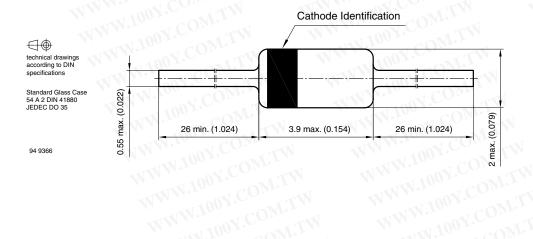


Figure 4. Typical Capacitance vs. Reverse Applied Voltage

# Package Dimensions in mm (Inches)

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Rev. 1.4, 03-Apr-06

# **BAT42 / BAT43**

#### **Vishay Semiconductors**



### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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